

/ Descriptions

PDFN3×3A-8L N MOS
N-Channel Enhancement Mode Field Effect Transistor in a PDFN3×3A-8L Plastic Package.

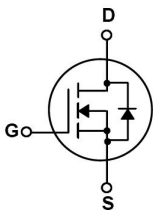
/ Features

$V_{DS} (V) = 30V$
 $I_D = 55 A (V_{GS} = \pm 20V)$
 $R_{DS(ON)}@10V \leq 5mR (Typ. 4.3mR)$
。 HF Product.

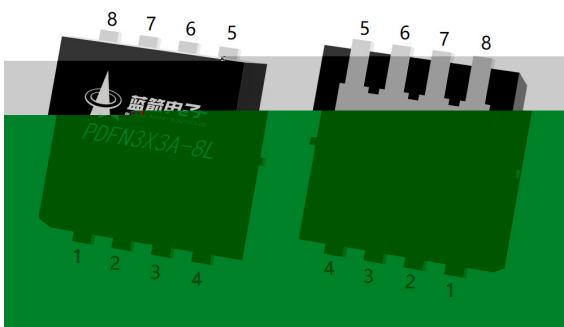
/ Applications

Load Switch Applications, Battery Power Management.

/ Equivalent Circuit



/ Pinning



出脚	定义
Pin1	S
Pin2	S
Pin3	S
Pin4	G
Pin5	D
Pin6	D
Pin7	D
Pin8	D

/ Marking

See Marking Instructions.

BRCS050N03YB

Rev.A May.-2023



DATA SHEET

Parameter		Symbol	Rating	Unit
Drain-Source Voltage		V_{DS}	30	V
Drain Current		$I_D(T_c=25^{\circ}\text{C})$	55	A
Drain Current - Pulsed		I_{DM}	145	A
Gate-Source Voltage		V_{GS}	± 20	V
Single Pulsed Avalanche Energy		E_{AS}	220.9	mJ
Avalanche Current		I_{AS}	23.5	A
Power Dissipation		$P_D(T_c=25^{\circ}\text{C})$	30	W
Operating and Storage Temperature Range		T_J, T_{stg}	-55 to 150	
Junction-to-Ambient	$t \leq 10$	$R_{\theta JA}$	40	$^{\circ}\text{C/W t}$

/ Electrical Characteristics(Ta=25)

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Drain-Source Breakdown Voltage	BV_{DSS}	$V_{GS}=0V$ $I_D=250\mu A$	30	35		V
Zero Gate Voltage Drain Current	I_{DSS}	$V_{DS}=30V$ $V_{GS}=0V$			1	μA
Gate-Body Leakage Current Forward	I_{GSS}	$V_{GS}=\pm 20V$ $V_{DS}=0V$			± 0.1	μA
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}$ $I_D=250\mu A$	1.0	1.8	2.5	V
Static Drain-Source On-Resistance	$R_{DS(on)}$	$V_{GS}=10V$ $I_D=20A$		4.3	5	m Ω
		$V_{GS}=4.5V$ $I_D=10A$		6.7	8	m Ω
Drain-Source Diode Forward Voltage	V_{SD}	$V_{GS}=0V$ $I_S=1A$			1.2	V
Input Capacitance	C_{iss}	$V_{DS}=25V$ $V_{GS}=0V$ $f=1.0MHz$		2030		pF
Output Capacitance	C_{oss}			168		
Reverse Transfer Capacitance	C_{rss}			163		
Gate resistance	R_g	$V_{GS}=0V$ $V_{DS}=0V$ $f=1MHz$		3.1		Ω
Total Gate Charge	$Q_{g(10V)}$	$V_{GS}=10V$ $V_{DS}=15V$ $I_D=20A$		40		nC
Total Gate Charge	$Q_{g(4.5V)}$			22		
Gate Source Charge	Q_{gs}			11		
Gate Drain Charge	Q_{gd}			5		
Turn-On Delay Time	$t_{d(on)}$	$V_{GS}=10V$ $V_{DS}=15V$ $R_L=0.75\Omega$ $R_{GEN}=3.0\Omega$		11		ns
Turn-On Rise Time	t_r			14		
Turn-Off Delay Time	$t_{d(off)}$			38		
Turn-Off Fall Time	t_f			10		

/ Electrical Characteristic Curve

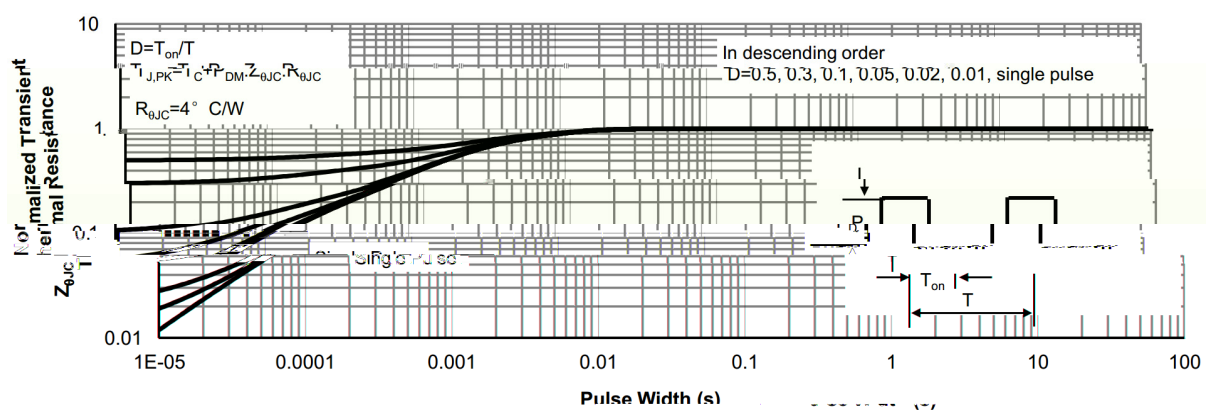
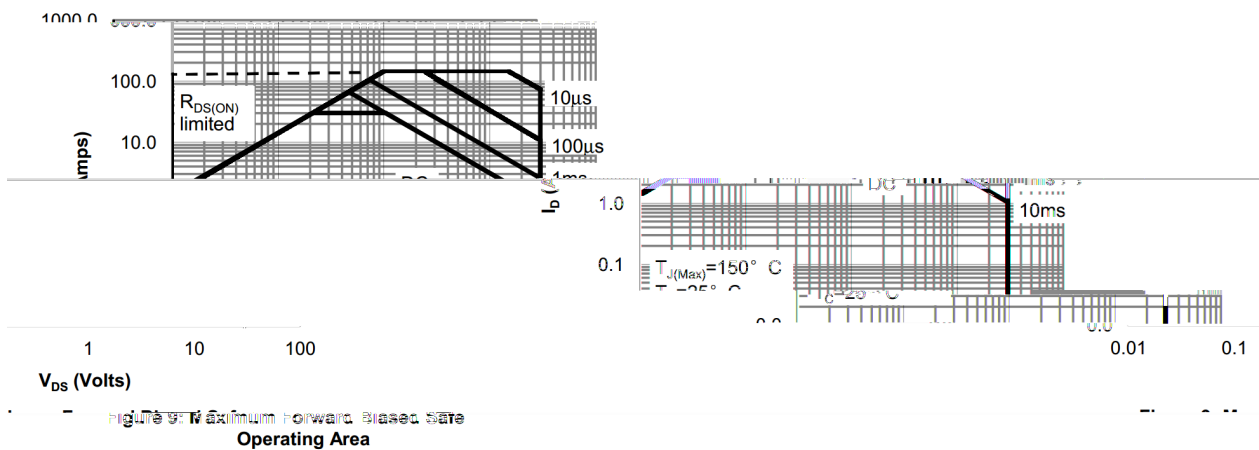
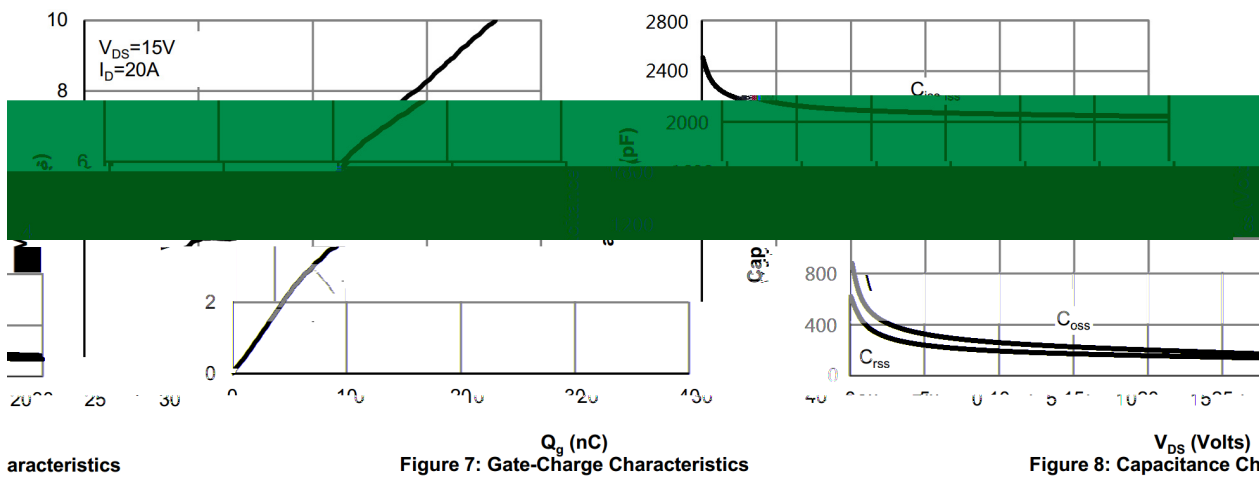
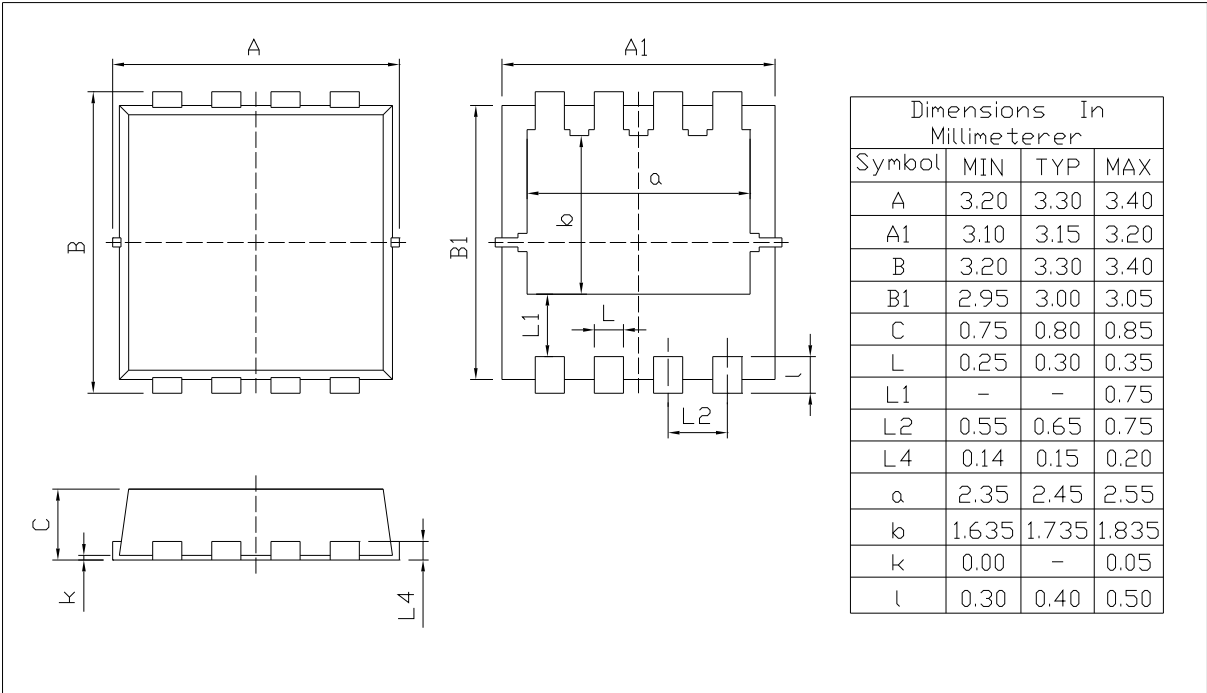


Figure 10: Normalized Maximum Transient Thermal Impedance

I Package Dimensions

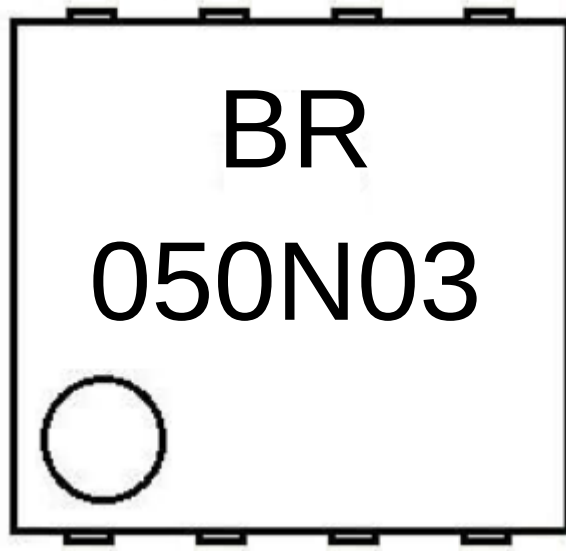
PDFN3X3A-8L

Unit:mm



Rev.00 202011

/ Marking Instructions



BR

050N03

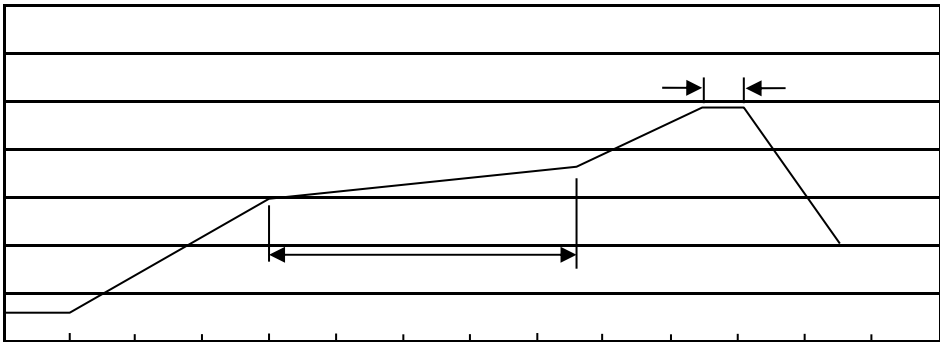
Note:

BR: Company Code

050N03: Product Type Code

****: Lot No. Code, code change with Lot No

() / Temperature Profile for IR Reflow Soldering(Pb-Free)



- 1

150 180

60 90sec;
- 2

245±5

5±0.5sec;
- 3

2 10 /sec.
- Note:

1.Preheating:150~180 , Time:60~90sec.

2.Peak Temp.:245±5 , Duration:5±0.5sec.

3. Cooling Speed: 2~10 /sec.

/ Resistance to Soldering Heat Test Conditions

260±5 10±1 sec. Temp.:260±5 Time:10±1 sec

/ Packaging SPEC.

/ REEL

Package Type	Units					Dimension (unit mm ³)		
PDFN3×3A-8L	5,000	2	10,000	6	60,000	13 ×12	360×360×50	380×335×366

/ Notices